Vacuum-ultraviolet 5*d*-4*f* luminescence of Gd³⁺ and Lu³⁺ ions in fluoride matrices

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The VUV 4 $f^{n-1}5d-4f^n$ luminescence and luminescence excitation spectra of Gd³⁺ (n=7) in LiGdF₄, GdF₃, LiYF₄:Gd³⁺, and YF₃:Gd³⁺, and of Lu³⁺ (n=14) in LiLuF₄, LuF₃, and LiYF₄:Lu³⁺ have been analyzed with high spectral resolution. In systems with intermediate electron-phonon coupling, zero-phonon lines, and phonon sidebands were observed. The excitation spectra of dilute systems exhibit rich fine structure originating from electronic origins of transitions and their phonon replica. Theoretical calculations explicitly taking into account a microscopic model of the crystal field and the crystal lattice vibrational spectra agree well with experimental data and are the basis for a safe analysis of the spectra.

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I. INTRODUCTION

Experiments on interconfigurational $4f^{n}-4f^{n-1}5d$ spectra of rare earth (RE) ions in large band gap matrices got started with the pioneering works of Feofilov¹ and Kaplyanskii and Feofilov² on the spectra of impurity divalent RE ions in alkaline-earth halides, as well as of Kaplyanskii *et al.*³ on the spectra of trivalent cerium in alkaline-earth fluorides. In 1966, $4f^{n} \rightarrow 4f^{n-1}5d$ transitions of almost all trivalent RE ions (except Pm³⁺, Gd³⁺, and Lu³⁺) in a CaF₂ matrix were reported by Loh.⁴ Except from Ce³⁺ and Pr³⁺, the transition energies are in the vacuum ultraviolet (VUV) spectral range where synchrotron radiation (SR) is the most powerful tool for spectroscopic researches.^{5,6} VUV SR was applied for the first time to the studies of RE³⁺ $4f^{n} \rightarrow 4f^{n-1}5d$ excitations by Elias *et al.*⁷ and Heaps *et al.*⁸

In the pioneering work of Yang and DeLuca,⁹ it was found that Nd³⁺, Er³⁺, and Tm³⁺, doped into fluorides, emit luminescence in the VUV spectral range, originating from $4f^{n-1}5d \rightarrow 4f^n$ radiative transitions (so-called 5d-4f luminescence). For the first half of the lanthanide series, transitions from the lowest $4f^{n-1}5d$ level into the $4f^n$ ground state are spin-allowed with short lifetimes (up to ≈ 50 ns). In the second half, such transitions are spin-forbidden (lifetimes in the μ s range) because the spin of the lowest $4f^{n-1}5d$ state (so-called high-spin state) exceeds the spin of the ground $4f^n$ configuration. However, depending on the ion and the host, spin-allowed emission from the higher-lying low-spin $4f^{n-1}5d$ state (with the same value of spin as in the ground $4f^n$ state) can be also observed.^{10,11}

Up to recently, RE³⁺ luminescence in VUV has been detected only from Nd³⁺, Er³⁺, and Tm³⁺. However, our studies¹²⁻¹⁴ have shown that VUV $5d \rightarrow 4f$ luminescence $(h\nu \sim 10 \text{ eV})$ is also observed from Gd³⁺ and Lu³⁺ ions doped into some fluoride hosts with sufficiently wide energy band gaps. The observation of 5d-4f luminescence from the

 Gd^{3+} ion is rather unexpected because of the considerable number of closely spaced $4f^7$ levels in the same energy region as the $4f^{6}5d$ states,¹⁵ potentially enabling nonradiative relaxation from the lowest $Gd^{3+} 4f^{6}5d$ level to lower-lying $4f^7$ levels. However, at low temperatures a rather intense VUV luminescence has been detected from several materials containing Gd^{3+} ions. The situation is different for the Lu^{3+} ion, which has only a single ${}^{1}S_0$ level of the ground $4f^{14}$ electronic configuration. The reason why $Lu^{3+} 5d$ -4f luminescence has never been detected earlier may arise from the fact that the corresponding photon energy is the highest among all RE³⁺ ions.

In the present paper, the results of a detailed investigation and characterization of VUV luminescence due to interconfigurational 5*d*-4*f* transitions in Gd^{3+} and Lu^{3+} ions in several fluorides are presented. In particular, results from stoichiometric Gd³⁺- and Lu³⁺ fluorides (GdF₃, LuF₃, LiGdF₄, and LiLuF₄) are compared with results from Gd³⁺ and Lu³⁺ doped fluorides (LiYF₄:Gd³⁺, YF₃:Gd³⁺, LiYF₄:Lu³⁺). Besides high-resolution luminescence spectra, allowing for an analysis of electron-phonon coupling, high-resolution excitation spectra have been measured as well. For comparison purposes, the Ce³⁺ ion with its simple electronic configuration in the LiYF₄ host has been included into our investigation. The phonon sidebands of the $Ce^{3+} 5d-4f$ transitions yield great similarities with those of the Gd³⁺ ion, indicating that the details of the coupling of the $4f^{n-1}5d$ configuration to the matrix mainly depend on the matrix and only to a minor extent to the ion incorporated.

A comparison of experimental spectra with results of simulations performed for LiYF_4 doped with Ce^{3+} and Lu^{3+} ions will also be presented. The spectral envelopes were obtained in the framework of the exchange charge model of the ion-lattice interaction by making use of the spectral densities of correlation functions for the relative displacements of the impurity ion and its nearest ligands (eight fluorine ions),

which were calculated with the parameters of the real phonon spectrum of the crystal lattice.

II. EXPERIMENTAL DETAILS

The measurements were performed at the SUPERLUMI station of HASYLAB at DESY, using SR from the DORIS storage ring¹⁶ for excitation. High-resolution VUV emission spectra were recorded with a 1-meter VUV monochromator and an open position-sensitive microchannel-plate (MCP) detector coated with CsI, at resolution intervals as small as 0.5 Å in second order.¹⁷ The spectra were not corrected for the spectral response of the detection system. However, taking into account that the measured spectra cover usually a rather narrow spectral region and that the spectral sensitivity is smooth in the spectral range of interest, we believe that such correction will not result in any remarkable changes in the shape of the spectra. The excitation spectra of VUV emission and decay curves were recorded with a Pouey-type monochromator (typical spectral resolution interval $\Delta\lambda$ =20 Å) equipped with a CsI sensitized microsphere-plate detector. By applying deconvolution techniques, a time resolution of the detection system better than 0.1 ns was achieved. 0.3 m Czerny-Turner monochromator-spectrograph А SpectraPro-308i (Acton Research Inc.) with a R6358P (Hamamatsu) photomultiplier tube (PMT) was applied for measuring excitation spectra of UV/visible luminescence. Emission spectra in the UV/visible spectral range were recorded at the same spectrograph with a liquid nitrogen cooled CCD detector (Princeton Instruments Inc.). With a 300 grooves/mm grating, a spectral resolution of ~ 1 nm was achieved. These spectra were also not corrected for the spectral response of the detection system, i.e., relative intensity of lines observed in different spectral ranges can differ from that presented here.

During the present work, the VUV monochromator has been recalibrated by atomic lines. Compared to earlier experiments,^{12,13} the absolute wavelength calibration was improved from ± 0.2 Å to ± 0.1 Å (corresponding to ± 7 cm⁻¹ at 82000 cm⁻¹). The relative accuracy of luminescence and excitation spectra is approximately the same because scattered light from the primary monochromator has been used for calibration of the secondary monochromators.

Single crystals of nominally pure LiGdF₄, LiGdF₄ doped with 0.05 at. % Ce³⁺, LiYF₄ doped with 0.5 and 2.0 at. %Gd³⁺, nominally pure LiLuF₄, LiYF₄ doped with 0.5, 1.0, and 5.0 at. % Lu³⁺, LiLuF₄ and LuF₃, both doped with 0.1 at. % Ce³⁺, were grown by the Czochralski and Bridgeman methods.^{18,19} Powder samples of LiYF₄ doped with 1.0 and 10.0 at. % Gd³⁺, and YF₃ doped with 1.0 at. % Gd³⁺, were obtained by the high temperature diffusion technique. GdF₃ and LuF₃ powder samples were high-purity chemicals with a concentration of unintentional RE and other metals of 0.0005–0.001 %, and an oxygen concentration of 0.02–0.05 %. The crystalline samples were cleaved prior to mounting on the sample holder attached to a flow-type liquid helium cryostat. All measurements have been performed in an UHV environment.



FIG. 1. Emission spectrum in the UV/visible/near IR range of the LiYF₄:Gd³⁺(10%) powder sample excited by VUV (120 nm) radiation at 9 K, measured with the CCD detector. The spectrum in the inset was measured with the Pouey-type VUV monochromator. The intensities of both spectra are arbitrary. The assignments of emission lines to the corresponding Gd³⁺ 4f⁷-4f⁷ transitions are given.

III. RESULTS AND DISCUSSION

A. 5d-4f transitions in Gd³⁺

1. Experimental results on LiGdF₄, LiYF₄:Gd³⁺, GdF₃, YF₃:Gd³⁺

As it was mentioned above, $Gd^{3+} 5d-4f$ luminescence was unexpected due to the fact that the $4f^7$ energy levels are very dense at high energies. Accordingly, it was supposed that radiative 5d-4f transitions in Gd³⁺ would be guenched due to energy transfer from d to f excitations and subsequent nonradiative relaxation into the lower f levels of Gd^{3+} from where emission takes place. Indeed, under VUV excitation, $Gd^{3+}f$ -f lines in the UV, visible, and IR are observed in the emission spectra of Gd³⁺-containing compounds (Fig. 1). In particular, the most intense line near 311 nm is due to transitions from the lowest excited $4f^{7} {}^{6}P_{7/2}$ level to the $Gd^{3+8}S_{7/2}$ ground state. The orange (590–640 nm) and IR (720-810 nm) luminescence, which are due to $4f^7$ ${}^{6}G_{7/2}$ - ${}^{6}P_{I}$ and ${}^{6}G_{7/2}$ - ${}^{6}I_{I}$ transitions in Gd³⁺,²⁰ are also observed under excitation to high energy levels of Gd³⁺. However, at low temperature, VUV luminescence around 10 eV has been detected as well from several gadolinium fluoride crystals.^{12–14} The energy level scheme and the main radiative and nonradiative transitions for the Gd³⁺ ion in some wide band gap (fluoride) hosts are shown in Fig. 2 (the energies of $Gd^{3+} 4f^7$ levels were taken from Ref. 21).

The VUV emission spectrum from the LiGdF₄ crystal (Fig. 3) has a well-resolved fine structure which shows at least seven lines spread over $\sim 500 \text{ cm}^{-1}$, extending into a wide sideband centered at $\sim 78\ 900 \text{ cm}^{-1}$. The shortest-wavelength line at $\sim 79\ 385\ \text{cm}^{-1}$ has varying intensity for different excitation energies because of reabsorption which changes depending on the penetration depth of the exciting radiation. The spectra are similar for undoped and Ce³⁺



FIG. 2. Energy level pattern illustrating Gd^{3+} excitation by VUV radiation (bold solid arrow), relaxation (dotted arrows), and observed luminescence (thin solid arrows) in a wide band-gap fluoride matrix. The shaded area covers a range with many closely-spaced *f* levels, which cannot be distinguished in this scale.

doped samples. The VUV emission from crystalline LiYF₄:Gd³⁺(0.5%) has nearly the same shape as that from the LiGdF₄ crystal but is slightly shifted to lower energies (by ~110 cm⁻¹). The spectra from LiYF₄:Gd³⁺ powder samples show only one pronounced line at ~79 220 cm⁻¹ and a wide sideband centered at ~78 900 cm⁻¹. The VUV emission spectra of GdF₃ and YF₃:Gd³⁺ are situated at higher photon energies and show single structureless bands centered at ~80 000 cm⁻¹ and ~79 700 cm⁻¹, respectively. The decay times of VUV luminescence from all Gd³⁺-containing samples are in the nanosecond range. At *T* ~10 K, the following decay times were measured: 2.8 ns for LiGdF₄, 2.5 ns for LiYF₄:Gd³⁺, 0.97 ns for GdF₃, and 1.1 ns for YF₃:Gd³⁺.

VUV luminescence from all Gd³⁺ compounds was observed only at low temperatures. As an example, in Fig. 4 the temperature dependence of the GdF₃ emission is shown. This dependence was approximated by the Mott formula, $I(T)/I(0) = [1 + A \exp(-\varepsilon_a/k_BT)]^{-1}$ (shown in the inset of Fig. 4). An activation energy $\varepsilon_a \sim 400 \text{ cm}^{-1}$ for thermal quenching was obtained from the fit. Around 200 K, the VUV luminescence is quenched completely. For LiYF₄:Gd³⁺, ε_a $\sim 530 \text{ cm}^{-1}$ and 620 cm⁻¹ for 10% and 1% doping concentrations were obtained. The values of ε_a are close to "characteristic" phonon energies of fluoride crystals, showing that the mechanism of thermal quenching can be treated as some kind of phonon-assisted nonradiative relaxation.



FIG. 3. High-resolution VUV emission spectra ($\Delta\lambda=0.8$ Å) of LiGdF₄ and LiYF₄:Gd³⁺(0.5%) single crystals, and of LiYF₄:Gd³⁺(1%), GdF₃ and YF₃:Gd³⁺(1%) powder samples. The excitation energies are given in the figure. *T*=10 K.

The excitation spectrum of VUV emission from LiGdF₄ single crystal has a well-pronounced onset at 79 000 cm⁻¹, overlapping with the shortest-wavelength line of the emission spectrum (Fig. 5). Hence, VUV luminescence is clearly correlated to the threshold of $Gd^{3+} 4f^7 \rightarrow 4f^65d$ excitation. Excitation spectra of UV/visible luminescence from LiGdF4 have rather rich fine structure. Their onsets are slightly below the onset of the VUV emission (UV/visible luminescence is also observed under direct f-f excitation, however, the signal is too weak to be observed with SR.). Excitation spectra of different Gd^{3+} emissions from LiYF₄: $Gd^{3+}(10\%)$ (powder sample) have no pronounced fine structure but show a distinct threshold. Excitation spectra of all kinds of Gd³⁺ luminescence from LiYF₄ (both powder and crystalline samples) weakly (0.5, 1, 2 %) doped with Gd^{3+} have identical thresholds and the same shape at least in the range 79 000-86 000 cm⁻¹where the fine structure is clearly observed in all these spectra. The fine structure is most pro-



FIG. 4. Temperature dependence of the VUV luminescence from GdF_3 . In the inset, the integrated intensity of the emission is plotted as a function of temperature, together with the simulation curve obtained as the best fit with the Mott formula.

nounced for the crystalline sample with the smallest (0.5%) concentration of Gd³⁺ (not shown).

The smooth-shaped excitation spectra of VUV emission from GdF₃ and YF₃:Gd³⁺ have their thresholds near 83 000 cm⁻¹ (Fig. 6). Similar to the case of LiGdF₄, excitation spectra of different kinds of luminescence from the stoichiometric compound GdF₃ have slightly different thresholds and shapes but all spectra lack fine structure. Excitation spectra of VUV and visible (595 nm) luminescence from YF₃:Gd³⁺ coincide in the region near and right above the threshold, whereas the excitation spectrum of UV (311 nm) luminescence from this material shows slightly different shape (Fig. 6).

2. Assignment of VUV luminescence to 5d-4f radiative transitions in Gd³⁺

The methodology proposed by Dorenbos²³ allows us to estimate the energy of the lowest 4f-5d transition in the RE³⁺ ion doped into a particular host if the value of this energy is known for any other RE³⁺ ion, e.g., for Ce³⁺, which has been extensively studied in many matrices. According to Ref. 23, the energy for the lowest spin-allowed 4f-5d transition in a RE³⁺ ion is given by

$$E^{\text{RE},s-a} = 49340 \text{ cm}^{-1} - D(A) + \Delta E^{\text{RE},\text{Ce}}$$
(1)

where 49 340 cm⁻¹ is the energy of the lowest 4f-5d transition in the free Ce³⁺ ion, D(A) is the crystal field depression energy for the compound A, and $\Delta E^{\text{RE,Ce}}$ is the energy difference between the first spin-allowed 4f-5d transition in the RE³⁺ and Ce³⁺ ions. The basis of this approximation is the fact that the crystal field depression is not sensitive to the individual ion, D(A) being an average of the $D(\text{RE}^{3+}, A)$ values for different RE³⁺ ions. In this approximation, the quantity $\Delta E^{\text{RE,Ce}}$ is independent from the host and can be regarded as an intrinsic property of the respective ion, being equal to 45 800 cm⁻¹ for $\Delta E^{\text{Gd,Ce},23}$ Using the energy difference between the maxima of broad Gaussian-like bands (cor-



FIG. 5. High-resolution excitation spectrum ($\Delta\lambda = 0.8$ Å) of the Gd³⁺ 5*d*-4*f* emission from LiGdF₄ (crystal), measured at 127 nm (78 740 cm⁻¹), together with the respective high-resolution emission spectrum excited by 119 nm (84 033 cm⁻¹) photons (upper part of the figure). All other curves are high-resolution excitation spectra of the Gd³⁺ ${}^{6}G_{7/2-}{}^{6}P_{7/2}$ emission at 593 nm from LiGdF₄ (crystal), from LiYF₄:Gd³⁺(10%) and LiYF₄:Gd³⁺(1%) (powder samples). *T*=10 K. The energy levels of the Eu³⁺⁷*F*_{*J*=0,6} multiplet in LiYF₄ (Ref. 22) are added for comparison (see text for details).

responding to strong electron-phonon coupling), the methodology can be applied only to GdF_3 and $YF_3:Gd^{3+}$. It can be extended, however, to the estimation of the energies of zerophonon lines (ZPLs) because the Stokes shift $\Delta S(A)$ between absorption and emission bands is characteristic for the host *A* but nearly independent from the RE³⁺ ion.²³ For LiGdF₄ and LiYF₄:Gd³⁺, the energies of the lowest 4*f*-5*d* ZPLs are therefore estimated according to

$$E_{ZPL}^{Gd} = E_{ZPL}^{Ce} + \Delta E^{Gd,Ce}.$$
 (2)

From the excitation spectrum of LiGdF₄ doped with 0.05% Ce³⁺, the ZPL energy of the lowest Ce³⁺ 4*f*-5*d* transition in LiGdF₄ (Fig. 7) was determined (33 615 cm⁻¹). The



FIG. 6. Excitation spectra ($\Delta\lambda=3$ Å) of Gd³⁺ 5*d*-4*f*, ⁶*P*_{7/2}-⁶S_{7/2} and ⁶*G*_{7/2}-⁶*P*_{7/2} emissions from GdF₃ and YF₃:Gd³⁺(1%) powder samples. *T*=10 K.

estimated energy of the ZPL of the lowest $Gd^{3+} 4f^7 - 4f^{6}5d$ transition then is 79 415 cm⁻¹, which is close to the threshold of the excitation spectrum of LiGdF₄ VUV emission as well as to the energy of the shortest-wavelength emission line from this crystal (79 385 cm⁻¹). Similar estimates for LiYF₄:Gd³⁺ yield 79 250 cm⁻¹ for the ZPL of the lowest Gd³⁺ 4f⁷-4f⁶5d transition, taking 33 450 cm⁻¹ for the ZPL of the lowest 4f-5d transition of Ce³⁺ in LiYF₄:Ce^{3+,24} The estimate agrees well with experiment (79 278 cm⁻¹).

For GdF₃ and YF₃:Gd³⁺, Eq. (1) can be applied directly. The depression energies of GdF₃ and YF₃ are 10 878 cm⁻¹ and 9915 cm⁻¹, respectively.²³ From Eq. (1), the lowest Gd³⁺ 4*f*-5*d* transition energies are 84 262 cm⁻¹ (GdF₃) and 85 225 cm⁻¹ (YF₃:Gd³⁺). Since the first broad maxima in the excitation spectra of Gd³⁺ 4*f*-5*d* emission in GdF₃ and YF₃:Gd³⁺ result from an overlap of transitions to various sublevels of the first crystal field 5*d* component, a comparison with the estimates will be misleading. However, the estimates may be better compared with the maxima in the VUV emission spectra, taking into account the Stokes shifts ΔS for these compounds given in Ref. 23, 5567 cm⁻¹ for GdF₃ and 5444 cm⁻¹ for YF₃. The estimated maxima of Gd³⁺ 5*d*-4*f* emission in GdF₃ and YF₃:Gd³⁺ are 78 695 and



FIG. 7. (a) High-resolution excitation spectrum of LiGdF₄: Ce³⁺(0.05%) monitoring Gd³⁺ ⁶P_{7/2} \rightarrow ⁸S_{7/2} 311 nm emission and calculated Ce³⁺ 4*f*-5*d* absorption spectrum of LiYF₄: Ce³⁺(0.05%) (upper wave number scale). (b) High-resolution VUV emission spectrum ($\Delta\lambda$ =0.8 Å) of LiGdF₄ (lower wave number scale). *T*=10 K.

79 781 cm⁻¹. For YF₃: Gd³⁺ the estimate agrees well with the experimental value (79 700 cm⁻¹). For GdF₃, the experimental value (80 000 cm⁻¹) exceeds the estimate considerably. Note, however, the energy parameters for Gd³⁺ 4*f*-5*d* transitions in GdF₃ given in Ref. 23 were obtained using data from a single paper and may therefore be less accurate than the parameters of YF₃: Gd³⁺, resulting in less reliable estimates.

Referring to the good agreement between theoretical estimates and experimental transition energies, the VUV luminescence observed is ascribed to Gd^{3+} transitions from the lowest $4f^{6} 5d$ level to the $4f^{7} {}^{8}S_{7/2}$ ground state. The assignment is supported by the following arguments. The VUV luminescence is observed in stoichiometric and weakly doped compounds, excluding an excitonic nature, which would be an alternative explanation. The decay time of a few nanoseconds is expected for the $4f^{6}$ 5d-4f⁷ radiative transitions in Gd³⁺, which are spin-allowed because the lowest $Gd^{3+} 4f^{6}5d$ level has the same spin as the ground state. Only one fast transition originating from the lowest $4f^{6}$ 5d level to the ground state is observed because of the absence of spin-orbit splitting for the ⁸S ground term of Gd³⁺. Transitions from the lowest $4f^{6}5d$ level to excited $4f^{7}$ levels are spin- and parity forbidden, i.e., the corresponding luminescence should be extremely weak. The crystal-field splitting of $Gd^{3+} 5d$ level in GdF_3 is expected to be smaller than in LiGdF₄ because of the higher coordination number for Gd³⁺

(9 instead of 8), and accordingly the $Gd^{3+} 4f^{6}5d-4f^{7}$ luminescence is observed at higher energy in GdF_{3} .

3. Specific nature of the 5d-4f luminescence from Gd³⁺: spin selection rules for nonradiative transitions, phonon fine structure

The dense $4f^7$ level system overlapping with the lowest $Gd^{3+} 4f^{6}5d$ level might open an efficient nonradiative relaxation channel, quenching the radiative decay. However, the rather strong emission intensities and the lifetimes in the ns range clearly show that the branching between radiative and nonradiative transitions favors the radiative decay at low temperatures. A selection rule must therefore suppress the nonradiative channel. The spin multiplicity of the lowest $4f^{6}5d$ level of Gd^{3+} is eight, whereas the $4f^7$ levels of Gd^{3+} closest to the $4f^{6}5d$ level are spin doublets or quartets.²⁵ As a consequence, the nonradiative channel is heavily spinforbidden.

The crystal-field splitting of the Gd³⁺ ground state is extremely small,²⁶ i.e.—within the spectral resolution interval—only one ZPL is expected in the Gd³⁺ VUV emission, corresponding to the electronic origin of the $4f^{6}5d-4f^{7} {}^{8}S_{7/2}$ transition. The 5d-4f luminescence spectra, however, yield several narrow lines, the origin of which is discussed below. For this purpose, the 5d-4f emission spectrum of LiGdF₄ is compared with the excitation spectrum for LiGdF₄:Ce(0.05%) at the edge of the Ce³⁺ f-d excitation (Fig. 7). A striking similarity is observed. This is also the case for LiYF₄:Gd³⁺. For the Ce³⁺ ion with only one 4felectron, a single ZPL is expected for 4f-5d absorption (excitation) to each crystal-field 5d component. All other structures arise from electron-phonon transitions (note the low doping level). The one-to-one correspondence between the Ce^{3+} excitation spectrum and the $Gd^{3+} 5d-4f$ emission proves that the fine structure in $Gd^{3+} 5d-4f$ emission is due to one ZPL and its phonon replica. The shape of the spectrum with a ZPL, a few narrow vibronic lines, and a wide lower-energy vibronic side band is typical for intermediate electron-phonon coupling. This is confirmed by an estimate of the Huang-Rhys parameter $S \sim 1$ from the energy difference between the ZPL and the maximum of the wide side band, taking into account the phonon spectrum of $LiGdF_4$.²⁷ An excellent agreement was obtained also between experimental spectra and calculations of the absorption spectrum for LiYF₄:Ce³⁺ (see Fig. 7). This will be discussed in Sec. III C.

The Stokes shift of $\sim 6000 \text{ cm}^{-1}$ observed in GdF₃ and YF₃:Gd³⁺ for Gd³⁺ 4f⁷-4f⁶5d transitions is more than 10 times larger than the maximum phonon energy in RE trifluorides,²⁸ i.e., the Huang-Rhys parameter *S* exceeds 5 in these matrices, corresponding to strong electron-lattice coupling. This explains the absence of any vibronic fine structure in the emission and excitation spectra.

4. Excitation spectra of Gd³⁺ 5d-4f luminescence and comparison with the energy level pattern of Eu³⁺

In this section, the excitation spectra presented in Fig. 5 will be discussed. They have a pronounced threshold origi-

nating from the onset of 4f-5d excitations (see Secs. III A 1 and III A 2). They all agree concerning the decrease at high energies. This decrease is due to the onset of host absorption. In between, however, two types of spectra are observed. One type yields a level of emission, which is nearly independent from the excitation energy. This is true for optically dense systems [either LiGdF₄ or LiYF₄:Gd³⁺(10%)], and an emission with a *fast* decay. The other type yields fine structure in an optically dense system (LiGdF₄) and a *slow* emission (593 nm) but also in an optically thin system [LiYF₄:Gd³⁺(1%)] with fast emission.

The first type corresponds to total absorption of the exciting radiation with subsequent relaxation into the emitting level. Provided the quantum efficiency is independent from the penetration depth of the exciting radiation, in this case no distinct fine structure can show up. It is well known, however, that energy transport towards the surface and surface quenching results in a modulation of excitation spectra with a correlation between minima in penetration depths (maxima in absorption) and minima in the excitation spectrum.²⁹ In the optically dense system LiGdF₄, both is observed: on a ns time scale, energy transport to the surface is obviously inefficient (5*d*-4f emission). On a time scale corresponding to the long lifetime of the 593 nm emission, energy transport to the surface and surface quenching modulates the excitation spectrum. The minima in the excitation spectrum are therefore ascribed to maxima of the absorption coefficient, whatever the nature of these maxima may be. The 5d-4f excitation spectrum in the optically thin system LiYF_4 : $\text{Gd}^{3+}(1\%)$ supports this statement. On a ns time scale, in the doped system the energy transport to the surface is even less efficient than in the optically dense system LiGdF₄. Therefore, the maxima observed are maxima in absorption. They are clearly correlated to the minima in the excitation spectrum of the 593 nm emission apart from the small matrix shift of 170 cm^{-1} (Sec. III A 1)]. More details will be given in a forthcoming paper.³⁰

The absorption maxima may be of electronic origin, they could originate from vibronic sidebands, or there may be a superposition of both. The splitting between distinct maxima is of the order of 1000 cm⁻¹, by far exceeding the splitting of vibronic sidebands as has been observed in the emission spectra (Sec. III A 3). Therefore, electronic excitations have to be considered. It is certainly too simple to discuss them in terms of the f^7 configuration which does not interact with the 5*d* level. On the contrary, the levels of the 4f ⁶5*d* configuration have to be taken into account.

To the best of our knowledge, no calculations of $4f^{7}$ - $4f^{6}5d$ transitions in Gd³⁺ were published in the literature. However, rather extensive studies have been performed for $4f^{7}$ - $4f^{6}5d$ transitions in Eu²⁺,^{31,32} which is isoelectronic to the Gd³⁺ ion. The structure observed for $4f^{7}$ - $4f^{6}5d$ transitions in Eu²⁺ was traced back to the energy level pattern of the $4f^{6}$ core in the $4f^{6}5d$ state. The levels of the $4f^{6}$ core were approximated by the well-known $4f^{6}$ level scheme of Eu³⁺. Rather good agreement between the measured peaks and the Eu³⁺ $4f^{6}$ levels was obtained.³¹

In analogy to the procedure of Ryan *et al.*,³¹ we included in Fig. 5 the Eu³⁺ $4f^{6}$ levels of LiYF₄:Eu³⁺ taken from Ref. 22 for comparison with the fine structure observed above threshold of $Gd^{3+} 4f^{7} - 4f^{6}5d$ excitation. The Eu^{3+} levels were arranged in a way that the $Eu^{3+} 4f^{6}$ ground state coincides with the $Gd^{3+} 4f^{7} - 4f^{6}5d$ ZPL. The energy range of the lower ${}^{7}F_{J}$ multiplets of the $Eu^{3+} 4f^{6}$ configuration matches well the energy spread for the Gd^{3+} electronic transitions under discussion. Therefore, the fine structure is ascribed to electronic levels of the $4f^{6}5d$ configuration. A one-to-one correspondence between the maxima and the Eu^{3+} levels, however, cannot be expected in view of the rudeness of the model.

B. 5d-4f transitions in Lu³⁺

1. Experimental results on LiLuF₄, LiYF₄: Lu³⁺, and on LuF₃ at low temperatures

VUV emission from the LiLuF₄ crystal consists of a line at $80\,910 \text{ cm}^{-1}$ and a wide sideband centered at $\sim 80 \ 180 \ \mathrm{cm}^{-1}$, whereas the luminescence spectrum from the LiYF₄:Lu³⁺(0.5%) crystal has a steep high-energy onset at \sim 81 100 cm⁻¹ followed by distinct lines and a sideband centered at $\sim 80\,630\,\mathrm{cm}^{-1}$, i.e. the emission spectrum from LiYF₄:Lu³⁺ is narrower than the one from LiLuF₄ (Fig. 8). The VUV emission from the LuF₃:Ce³⁺ single crystal and from the undoped powder sample of LuF3 consists of a single broad band centered at $\sim 80500 \text{ cm}^{-1}$ (Fig. 9). VUV luminescence from all studied lutetium compounds has a long lifetime beyond the experimental limit (longer than $\sim 1 \ \mu s$) and is thermally quenched near 200 K. The VUV luminescence is ascribed to $Lu^{3+} 5d-4f$ transitions. The long lifetime indicates a spin-forbidden character of 5d-4f transition. The assignment will be confirmed in Sec. III B 2.

The excitation spectrum of VUV emission from the LiLuF₄ crystal has a smooth rise above 81 000 cm⁻¹ with some faint structures, and two pronounced peaks at 81 760 and 83 150 cm⁻¹ (Fig. 8). In the case of LiYF₄:Lu(5%), a steep threshold at 81 760 and two lines just above threshold at 81 950 cm⁻¹ and 82 240 cm⁻¹ are observed. An additional pronounced rise shows up at 83 170 cm⁻¹. At the low-energy side of the 81 760 cm⁻¹ threshold, weak features are observed in an enlarged scale, corresponding to the faint structures of the rising part of the LiLuF₄ spectrum. The excitation spectrum of the LuF₃ 5*d*-4*f* luminescence has a threshold near 82 700 cm⁻¹ and does not show any fine structure (Fig. 9).

2. Assignment of VUV luminescence to 5d-4f radiative transitions in Lu³⁺

The energies for the lowest $Lu^{3+} 4f-5d$ transitions in LiLuF₄ and in the LiYF₄ matrix are estimated according to²³

$$E_{ZPL}^{Lu,s-a} = E_{ZPL}^{Ce} + \Delta E^{Lu,Ce}.$$
(3)

 $\Delta E^{Lu,Ce}$ =49 170 cm⁻¹ given in Ref. 23 may be rather uncertain because it is solely based on one paper on gaseous Lu³⁺. The energies of the ZPLs for Ce³⁺ 4*f*-5*d* transitions (33 130 cm⁻¹ in LiLuF₄:Ce³⁺ and 33 450 cm⁻¹ in LiYF₄:Ce³⁺) are taken from Ref. 24. Equation (3) then yields the values of the spin allowed Lu³⁺ 4*f*¹⁴-4*f*¹³5*d* ZPLs



FIG. 8. High-resolution VUV emission spectra ($\Delta\lambda=0.8$ Å) from LiYF₄:Lu³⁺(0.5%) (a) and LiLuF₄ (b) single crystals, together with the respective high-resolution excitation spectra. In the case of LiYF₄:Lu³⁺, a sample with 5% concentration of Lu³⁺ ions was chosen for excitation spectrum measurement in order to get a stronger signal in the range from 81 000 cm⁻¹ to 81 750 cm⁻¹. This part of the excitation spectrum is shown also in enlarged (×30) scale. *T*=11.5-12 K.



FIG. 9. High-resolution VUV emission spectrum and excitation spectrum of VUV emission from LuF_3 powder sample. T=11 K.

in LiLuF₄ and LiYF₄:Lu³⁺: 82 300 and 82 620 cm⁻¹. These values are considerably larger than the energies of the pronounced maxima in the excitation spectra below 82 000 cm⁻¹. In view of the uncertainly of $\Delta E^{Lu,Ce}$, it is not possible to take the estimates as the basis for an assignment of any structure to a ZPL. However, the estimates clearly prove that the strong signals in the excitation spectra around 82 000 cm⁻¹ arise from spin-allowed transitions in Lu³⁺ from the 4*f* ¹⁴¹S₀ state to the lowest low-spin (*S*=0) state of the excited 4*f* ¹³5*d* configuration.

The calculations following the methodology of Dorenbos can be extended to the spin-forbidden 4f-5d transitions since the energy difference, $\Delta E_{RE}^{sa,sf}$, between the spin-allowed and the spin-forbidden 4f-5d excitation energy is merely a property of the respective ion but is nearly independent on the host

$$E_{ZPL}^{Lu,s-f} = E_{ZPL}^{Ce} + \Delta E^{Lu,Ce} - \Delta E_{Lu}^{sa,sf}.$$
 (4)

Unfortunately, the value of $\Delta E_{Lu}^{sa,sf}$ is not known. However, taking into account the decreasing trend of the energy splitting between spin-allowed and spin-forbidden 4f-5dtransitions from Tb³⁺ to Yb³⁺, and that in Yb³⁺ this splitting is of the order 1500 cm⁻¹,³³ we have reasons to argue that $\Delta E_{Lu}^{sa,sf} \leq 1500$ cm⁻¹. The estimates of ZPL energies for spinforbidden Lu³⁺ 4f-5d transitions in LiLuF₄ and LiYF₄ hosts are >80 800 cm⁻¹ and >81 120 cm⁻¹, respectively. The lower limits of these estimates are close to the weak features observed in the excitation spectra of LiLuF₄ and LiYF₄:Lu³⁺ and to the high-energy tails of the respective luminescence curves. The VUV emission is therefore ascribed to spinforbidden transitions from the lowest high-spin (*S*=1) level of the $4f^{13}5d$ configuration to the Lu³⁺ $4f^{14-1}S_0$ ground state.

In contrast to LiGdF₄ and LiYF₄: Gd³⁺ where strong ZPLs at the short wavelength edges of spectra are clearly observed, the 5*d*-4*f* spectra from LiLuF₄ and LiYF₄: Lu³⁺ do not show ZPLs (within the experimental sensitivity). The shortwavelength tail of the Lu³⁺ 5*d*-4*f* emission overlaps with the long wavelength tail of the weak structure in the excitation spectrum. Obviously, the transition probability for the pure electronic spin-forbidden transition is extremely small, so that only phonon-assisted transitions show up in the spectra. The sharp lines observed in Lu³⁺ 5*d*-4*f* luminescence in LiLuF₃ and LiYF₄:Lu³⁺ are therefore ascribed to phononassisted transitions, merging into a sideband. The electronic origin may be estimated from the crossing of the emission and excitation spectra (~81 000 cm⁻¹). The absence of the ZPL will be further discussed in Sec. III C.

Concerning LuF₃, the VUV emission is ascribed as well to the spin-forbidden Lu³⁺ 5*d*-4*f* transitions. Whereas the shape of the emission band corresponds to the strong coupling case, the first excitation band observed in the excitation spectrum is not the counterpart of emission but is mainly due to a convolution of spin-allowed excitations into different crystal field components. Therefore, e.g., the energetic difference between the maxima in emission (80 500 cm⁻¹) and excitation (87 000 cm⁻¹) does not correspond to the Stokes shift. One may speculate that the asymmetric shape of the



FIG. 10. Temperature dependence of the Lu³⁺ VUV emission $(\Delta\lambda \sim 2 \text{ Å})$ from LiYF₄:Lu³⁺(1%) single crystal in the temperature range from 8.3 to 220 K, excited by 118 nm (84 750 cm⁻¹) photons; high-resolution excitation spectra of the low- and high-energy VUV emissions from LiYF₄:Lu³⁺(0.5%) crystal at temperatures 8.2 and 169 K.

excitation spectrum around $84\,000 \text{ cm}^{-1}$ arises from the spin-forbidden excitation band, indicating a rough estimate of the Stokes shift 4000 cm⁻¹ and an electronic origin at 82 000 cm⁻¹.

Although no ZPLs are observed, the fine structure of the luminescence spectra of LiLuF₄ and LiYF₄:Lu³⁺ indicates intermediate coupling. Taking into account the estimate of the electronic origin, the effective phonon frequencies (400 cm⁻¹) (Ref. 27) of the respective lattice and the energetic position of the smooth luminescence sidebands, $S \sim 2$ is obtained. The Stokes shift between absorption and emission for $4f^{13}5d-4f^{14}$ transitions in LuF₃ (~4000 cm⁻¹) is considerably larger than in LiYF₄ and LiLuF₄, i.e., Huang-Rhys parameter S > 5 in LuF₃, which is in agreement with strong coupling (absence of any vibronic fine structure).

3. Temperature dependence of Lu³⁺ 5d-4f luminescence

As already mentioned, $Lu^{3+} 5d-4f$ luminescence in the materials studied is thermally quenched at temperatures T > 200 K. However, as a function of temperature, an additional higher-energy emission band appears at temperatures T > 100 K. This band is observed from all studied Lu^{3+} -containing compounds independent of the Lu^{3+} concentration, i.e., this is the property of the Lu^{3+} ion but not of the matrix. The results for LiYF₄: Lu^{3+} are shown in Fig. 10. Compared to Fig. 8, the vibronic structures are broader. This is not only due to the larger resolution interval used (2 Å) but also to thermal broadening. The excitation spectrum measured at 8.2 K broadens as well at elevated temperatures. At intermediate temperatures where both bands coexist, the excitation spectra of both bands coincide.

As was discussed above, the transition probability for spin-forbidden 5d-4f radiative transitions from the lowest high-spin (S=1) 4f ¹³5d state of Lu³⁺ is very small. However, with increasing temperature, an additional decay channel for the lowest 4f ¹³5d level is opened, namely thermal population of the higher-lying low spin (S=0) 4f ¹³5d state, from which the 5d-4f raditive transition is spin-allowed. The additional emission band observed is ascribed to the spin-allowed 5d-4f luminescence.

Under thermal equilibrium population of both levels, the intensity ratio for the emission from these levels is determined by the ratio of products of the level population and transition probability from the level. Since the energy separation between high- and low-spin $4f^{13}5d$ states in Lu³⁺ is small (as a rough approximation, either the energy separation of the envelopes of both bands or the estimates of electronic origins in Sec. III B 2 may be taken), the emission from the low-spin $4f^{13}5d$ state can become intense at rather low temperatures. At $T \sim 150$ K (LiYF₄:Lu³⁺), the intensities of both bands are approximately the same. For the level separation of 823 cm⁻¹ obtained from calculations (see Sec. III C below), the ratio of transition probabilities for spin-allowed and spin-forbidden 5*d*-4*f* transitions is estimated as being ~ 3 $\times 10^3$, which is reasonable. It should be noted that due to the specific mechanism of population of this low-spin $4f^{13}5d$ state, the decay kinetics for the high-energy band is controlled by lifetime for spin-forbidden transition and accordingly is slow. A similar effect was observed for Er³⁺ spinallowed and spin-forbidden 5d-4f luminescence from the $LiYF_4$: Er^{3+} crystal³⁴ but at much higher temperatures \sim 800 K, since the splitting between high- and low-spin 5d states of the Er^{3+} ion is ~3300 cm⁻¹.³³

4. Excitation spectra of Lu³⁺ 5d-4f luminescence

In this section, only a few aspects of the excitation spectra (Fig. 8) will be discussed. The excitation spectrum of $Lu^{3+} 5d-4f$ emission in LiYF₄: $Lu^{3+}(5\%)$ yields pronounced maxima which are ascribed to crystal-field components and phonon sidebands of the $4f^{13}5d$ configuration. More details are given in Sec. III C where the spectrum will be compared with calculations.

The most striking features of the LiLuF₄ spectrum are the maxima at 81 760 cm⁻¹ and 83 150 cm⁻¹. In an earlier publication, they were ascribed to ZPLs of spin-forbidden and spin-allowed Lu³⁺ $4f^{14}$ - $4f^{13}5d$ transitions.²⁴ In view of the new results of the present paper, this interpretation is no longer valid. The pronounced peaks correspond well to the thresholds observed in the excitation spectrum of the dilute system LiYF₄:Lu³⁺(5%) (Fig. 8). Hence, they correspond to excitation with large penetration depths where all kind of surface quenching is of minor importance. Indeed, the general behavior of the LiLuF₄ spectrum can be modeled, taking into account diffusive-type energy transfer from the bulk to the surface and surface quenching. The strong peaks arise from excitations in the bulk, which are not affected by surface quenching. More details are given elsewhere.³⁰

C. Electron-phonon interaction in the $4f^{n-1}5d$ electronic configurations of RE³⁺ ions and simulations of the $4f^{n}-4f^{n-1}5d$ spectra

1. General theory of electron-vibrational $4f^{n}-4f^{n-1}5d$ spectra in the adiabatic approximation

To simulate interconfigurational 4f-5d spectral envelopes, we use the approach derived in Ref. 35 and generalized for

the spin-forbidden transitions. This approach involves calculations of crystal field parameters for a 5d electron as explicit functions of lattice ion's coordinates in the framework of the exchange charge model,³⁶ numerical diagonalization of the effective impurity ion Hamiltonian containing energies of electrostatic Coulomb and exchange interactions between electrons, spin-orbit interactions and the crystal field interactions for the ground $(4f^n)$ and excited $(4f^{n-1}5d)$ electronic configurations; calculations of the 5d-electron-phonon coupling constants, and simulations of the band shapes by making use of the realistic phonon spectrum of the host crystal lattice. The crystal field model was improved, in comparison with Ref. 35, by taking into account the extended charge distributions of a 5d electron and ligands' outer electrons in calculations of the electrostatic component of the ligand field.³⁷ An energy gap Δ between the excited and ground configurations is treated as a fitting parameter. The Hamiltonian of the 5d-electron-phonon interaction, linear in dynamic displacements u(Ls) of the lattice ions

$$H_{el-ph} = \sum_{L,s,\alpha} V_{\alpha}(Ls) [u_{\alpha}(Ls) - u_{\alpha}(00)]$$
(5)

[here unit cells and ions in the cell are labeled by L and s, respectively, with the impurity ion having the (00) label] is considered within the cluster approximation: modulation of the crystal field by ligand vibrations is considered only. The electronic operators $V_{\alpha}(Ls)$ are defined by the coupling constants, which can be obtained by direct differentiation of corresponding crystal field parameters with respect to the lattice ion coordinates. Lattice vibrations are considered in the harmonic approximation.

The shape of the absorption/emission spectrum at low temperatures is easily obtained within the adiabatic and Condon approximations. The electron-phonon interaction is considered as a perturbation in the electron equation of the adiabatic approximation, and zero order electronic functions are exploited in calculations. The absorption coefficient $K_{ab}(\Omega)$ at the radiation frequency Ω for the electric dipole $a(4f^n) \rightarrow b(4f^{n-1}5d)$ transition, allowed in the Condon approximation, is proportional to the product of the normalized absorption form function³⁸

$$F_{ab}(\Omega) = 2\pi e^{-S_b} \sum_{p=0}^{\infty} M_{p,b}(\Omega - \Omega_{ba})$$
(6)

and the integral intensity of the transition given by $|\langle b(5d) | \mathbf{d} \boldsymbol{\epsilon} | a(4f) \rangle|^2$, where $\boldsymbol{\epsilon}$ is the polarization vector of radiation, \boldsymbol{d} is the effective electric dipole moment of an ion, $M_{p,b}$ represents a *p*-phonon contribution to the spectrum: $M_{0,b}(\Omega - \Omega_{ba}) = \delta(\Omega - \Omega_{ba})$, and for p > 0 and any b_1 , b_2 , b_3 , b_4 states from the $4f^{n-1}5d$ configuration

$$M_{p,b}(\Omega - \Omega_{ba}) = \frac{1}{(\pi \hbar)^p p!} \int \frac{d\omega_1}{\omega_1^2} \cdots \frac{d\omega_p}{\omega_p^2} D_{bbbb}(\omega_1) \dots D_{bbbb}(\omega_p) \\ \times \delta(\Omega - \Omega_{ba} - \omega_1 \dots - \omega_p),$$
(7)

$$D_{b_1 b_2 b_3 b_4}(\omega) = \sum_{Ls\alpha} \sum_{L's'\beta} \langle b_1 | V_{\alpha}(Ls) | b_2 \rangle g_{\alpha\beta}(Ls, L's' | \omega)$$
$$\times \langle b_3 | V_{\beta}(L's') | b_4 \rangle * . \tag{8}$$

The form function of the emission spectrum is obtained from (6) by substituting $2\Omega_{ba}-\Omega$ for Ω . Functions $g_{\alpha\beta}(Ls,L's'|\omega)$ in Eq. (8) represent spectral densities of correlation functions for the relative dynamic displacements of ions in the cluster.³⁵ The integral intensity of a ZPL at the frequency Ω_{ba} , which corresponds to the energy gap E_b $-E_a$ (*E* is the crystal field energy) diminished by the Jahn-Teller (JT) energy $E_{JT}(b) = -\frac{1}{\pi} \int D_{bbbb}(\omega) \frac{d\omega}{\omega}$, is determined by the Huang-Rhys parameter $S_b = \frac{1}{\pi\hbar} \int D_{bbbb}(\omega) \frac{d\omega}{\omega^2}$. The effective number of *p*-phonon bands, to be considered explicitly in the simulation of the form-function $F_{ab}(\Omega)$, may be approximated as $p_{max} = 2S_b$.

To derive the absorption/emission form-function at the radiation frequency Ω for the spin-forbidden electric dipole $a(4f^n) \leftrightarrow b(4f^{n-1}5d)$ transitions, we consider the electronic wave function of the *b* state in the first order in perturbation H_{el-ph} . The corresponding non-Condon form function is determined by dynamic admixture of all other $4f^{n-1}5d$ states to the *b* state, and can be obtained in the following form:

$$\begin{split} K_{ab}^{(f)}(\Omega) &\sim F_{ab}(\Omega) \left| \int \varphi(\omega) d\omega \right|^2 + \int F_{ab}(\Omega \mp \omega) \\ &\times \left\{ f(\omega) \mp 2 \operatorname{Re} \left[\varphi(\omega) \int \varphi(\omega') * d\omega' \right] \right\} d\omega \\ &+ \int \int F_{ab}(\Omega \mp \omega \mp \omega') \varphi(\omega) \varphi(\omega') * d\omega d\omega', \end{split}$$

$$\end{split}$$
(9)

where upper and lower signs should be used for the absorption and emission, respectively, and

$$f(\omega) = \sum_{c',c\neq b} \frac{\langle c | \mathbf{d}\boldsymbol{\varepsilon} | a \rangle \langle c' | \mathbf{d}\boldsymbol{\varepsilon} | a \rangle^*}{(E_b - E_c)(E_b - E_{c'})} \frac{\hbar}{\pi} D_{cbc'b}(\omega), \quad (10)$$

$$\varphi(\omega) = \sum_{c \neq b} \frac{\langle a | \mathbf{d}\boldsymbol{\varepsilon} | c \rangle}{E_b - E_c} \frac{1}{\pi \omega} D_{cbbb}(\omega). \tag{11}$$

Here the sums are taken over all $4f^{n-1}5d$ states, different from the state *b*. Unlike the case of the allowed transitions, not only the integral intensities of the forbidden $a(4f^n) \leftrightarrow b(4f^{n-1}5d)$ spectral bands depend on the *a* state, but also their line shapes, even though we neglect the electron-phonon interaction in the $a(4f^n)$ state. As it follows from Eq. (9), a possibility to observe directly the form function $F_{ab}(\Omega)$ and the corresponding ZPL at the frequency Ω_{ba} depends on the dimensionless ratios $|\int D_{cbbb}(\omega) \frac{d\omega}{\pi\omega}/(E_c - E_b)|$ which may be essentially less than unity due to lower values of spectral cross-distributions $D_{cbbb}(\omega)$ in comparison with the autodistributions $D_{bbbb}(\omega)$ and $D_{cbcb}(\omega)$. In a general case, the mirror symmetry between the spin-forbidden

TABLE I. Spin-orbit coupling constants and crystal field parameters in $LiYF_4$: Ce^{3+} and $LiYF_4$: Lu^{3+} (in cm^{-1}).

	Ce ³⁺	Lu ³⁺	
$\overline{\zeta(4f)}$	625	3406	
$B_0^2(4f)$	360	380	
$B_0^4(4f)$	-1400	-600	
$B_4^4(4f)$	-1240+750i	-590+510i	
$B_0^6(4f)$	-67.2	-36.8	
$B_4^6(4f)$	-1095+458i	-413 + 254i	
$\zeta(5d)$	1082	1939	
$B_0^2(5d)$	2454	2207	
$B_0^4(5d)$	-16494	-13027	
$B_4^4(5d)$	-17323 + 17020i	-13515 + 13332i	

absorption and emission spectra is broken due to different signs of the third term at the rhs of Eq. (9).³⁸

2. Simulations of the electron-vibrational spectra in LiYF₄:Ce³⁺ and LiYF₄:Lu³⁺

Following the general approach described above, we have calculated the energy level patterns of the excited configurations and shapes of the electron-vibrational f-d absorption and emission spectra at low temperatures for the impurity Ce^{3+} and Lu^{3+} ions in LiYF₄.

Trivalent RE ions substitute for Y^{3+} ions in LiYF₄ crystals in sites with S_4 point symmetry. The energy level patterns of the excited configurations $5d^1$ (Ce³⁺) and $4f^{13}5d^1$ (Lu³⁺) contain five Kramers doublets (in the tetragonal crystal field, the 5*d* orbital manifold splits into three singlets and a doublet which is split further by the spin-orbit interaction), and 70 singlets and 35 non-Kramers doublets, respectively.

Parameters used in the calculations of the crystal field energies of the excited Ce³⁺ and Lu³⁺ configurations are listed in Table I. The spin-orbit coupling constants $\zeta(4f)$ and $\zeta(5d)$ were taken from the literature.^{39,40} The crystal field parameters were calculated using the analytical radial 5dfunctions from Refs. 41 and 42 and 2s, 2p functions of the F^- ion from Ref. 43. Ion charges were fixed as -1 (F^-), +1 (Li⁺), +3 (Y^{3+}). Parameters of the exchange charge model $G_s = 1.69$ (Ce³⁺) and 1.55 (Lu³⁺), $G_{\sigma} = 2.45$ and G_{π} =0.13, the overall energy shift of the 5*d* configuration Δ =43 827 and 104 493 cm⁻¹ for Ce³⁺ and Lu³⁺, respectively, and the parameters of the Coulomb $[F^{(2)}(fd)=19727 \text{ cm}^{-1}]$ $F^{(4)}(fd) = 10\,477 \text{ cm}^{-1}$ and exchange $[G^{(1)}(fd) = 4662 \text{ cm}^{-1}]$, $G^{(3)}(f d) = 5640 \text{ cm}^{-1}, G^{(5)}(f d) = 7087 \text{ cm}^{-1}$ interactions between the electrons (for the Lu³⁺ ion) were obtained from fitting the calculated spectra to the experimental data. Since the shift of a vibronic band maximum from a ZPL roughly compensates for the Jahn-Teller energy, the calculated crystal field energies were fitted to the positions of the corresponding vibronic band maxima. For the impurity Ce³⁺ centers, a radial local deformation of the crystal lattice was taken into account (the RE ion - ligand distances were enlarged by about 3%).44

State Number	$E_{\rm CF}$ (cm ⁻¹)	$E_{\rm JT}$ (cm ⁻¹)	<i>E</i> (ZPL) (cm ⁻¹)	The Huang- Rhys parameter	Relative intensity $\sigma(\varepsilon \ a)$	Relative intensity $\pi(\varepsilon \ c)$
1	81391	-263	81127	1.29	$0 (1.54 \cdot 10^{-3})$	0 (6.10-4)
2	81404	-264	81140	1.29	$0(1.76 \cdot 10^{-3})$	$0 (6 \cdot 10^{-3})$
3, 4	82154	-205	81950	0.96	0.530	0
5	82620	-162	82458	0.73	0	$5 \cdot 10^{-5}$
6, 7	83649	-300	83349	1.49	6.444	0
8	83923	-326	83597	1.63	0	2.057
9	84218	-269	83950	1.31	0	0.003
10, 11	84339	-288	84052	1.41	0.181	0
12	84541	-257	84285	1.23	0	3.872
14, 15	84903	-235	84667	1.12	0.923	0

TABLE II. Spectral characteristics of the low-energy $Lu^{3+} 4f^{13}5d$ states.

The correlation functions for relative displacements of the impurity RE^{3+} ion and its nearest neighbors were computed in the framework of the lattice dynamics model of the LiYF₄ crystal derived in Ref. 27. To compare the simulated spectral envelopes with the measured spectra, form-functions (7) were convoluted with a Gaussian to take into account the inhomogeneous broadening (~25 cm⁻¹) induced by random lattice strains and with a Lorentz distribution to account for the relaxation broadening (the homogeneous widths were estimated from calculations of spontaneous one-phonon transition probabilities).

The calculated integral intensities and positions of the maxima of the electron-vibrational 4f-5d bands in the ground state absorption spectra of LiYF₄:Ce³⁺ at low temperatures agree satisfactorily with the experimental data.^{35,45} The calculated Huang-Rhys parameters for the 5d crystal field states of Ce³⁺ ion in LiYF₄ equal 2.9, 17.4, 6.0, 6.0, 16.4, with the smallest value for the lowest 5d state, thus explaining why the ZPL is observed only in the transitions which involve this state, while all other 4f-5d bands can be approximated well by smooth Gauss distributions with different widths.⁴⁵ The simulated line shape for the 4f-5d absorption to the lowest 5d state in LiYF₄:Ce³⁺ with the well pronounced fine structure is in a good agreement with the measured shape of the excitation spectrum of Ce³⁺ luminescence in LiGdF₄:Ce³⁺ (Fig. 7) as well.

The calculated crystal field energies of the Lu³⁺ 4 $f^{13}5d$ configuration spread over the range 81 000 cm⁻¹ – 113 000 cm⁻¹, with nearly 90% of absorption intensity being in the second half of the spectrum. The structure of the spectrum follows general regularities found in the spectra of RE-doped LiYF₄ crystals.³⁵ Three groups of states can be distinguished: 16 states from 81 000 to 84 700 cm⁻¹, weakly coupled to phonons (with the Huang-Rhys parameters from 0.7 to 1.6); 16 states from 87 400 to 90 700 cm⁻¹, strongly coupled to phonons (with the Huang-Rhys parameters from 4.5 to 7.6); the continuum of mixed electron-phonon states distributed in the range of energies from 93 000 to 113 000 cm⁻¹, with the Huang-Rhys parameters varying from 0.4 to 7 (these levels interact strongly with the nonadiabatic phonons).

The observed excitation spectrum (see Fig. 8) corresponds to the first group of the $4f^{13}5d$ states. In Table II we present calculated characteristics for the states from this group, which have nonzero absorption intensity: the number of a state, the crystal field energy $E_{\rm CF}$, the Jahn-Teller energy $E_{\rm JT}$, the ZPL frequency, the Huang-Rhys parameter, and the relative integral intensities of the σ and π polarized electricdipole transitions [the squared matrix elements of the first rank spherical operators between the ${}^{1}S_{0}(4f^{-14})$ ground state and the corresponding $4f^{-13}5d$ state].

The simulated (the inhomogeneous broadening width of 28 cm⁻¹ was introduced) nonpolarized absorption spectrum corresponding to allowed transitions from ${}^{1}S_{0}(4f^{14})$ to lower sublevels of the $4f^{13}5d$ configuration of Lu³⁺ in LiYF₄ is compared with the experimental excitation spectrum in Fig.



FIG. 11. (a) The low temperature simulated $Lu^{3+} 4f-5d$ spinallowed absorption spectrum (1, thin solid curve). (b) The modeled (2, bold solid curve) and the measured (3, dashed curve) excitation spectra of LiYF₄:Lu³⁺(5%).

11. At first sight, there seems to be a significant discrepancy in calculated and experimental transition intensities. However, we have to take into consideration that $LiYF_4$: $Lu^{3+}(5\%)$ reaches optical saturation at least in the peaks of the spin- and parity-allowed 4f-5d transitions. Therefore, from the theoretical absorption curve $K(\Omega)$, the actual excitation spectrum has been estimated by {1 $-\exp[-K(\Omega)d]$, where d is the crystal thickness (curve 2 in Fig. 11). As the absorption curve was calculated in arbitrary units, d was treated as a parameter. It was adjusted in a way that the relative height of the main maxima is reproduced. The overall agreement is satisfactory, though it is clear that the simulated ZPLs are more pronounced than the measured ones; the reason for the discrepancy may be that we have not taken into account interactions of crystal field doublets with nonadiabatic phonons.

The low energy intensive band in the excitation spectrum of LiYF₄:Lu³⁺(5%), with a narrow line at 81 950 cm⁻¹, is ascribed to the spin-allowed transitions to the lowest (3,4) doublet. The energy gap Δ was chosen so that the corresponding ZPL coincides with the observed narrow line. The maximum of the simulated vibronic band is at 82 327 cm⁻¹, greater than the experimental value by about 100 cm⁻¹. The next intensive band in the excitation spectrum has 5 pronounced maxima. We list their energies with the assignment (the state number) in parentheses: 83 345 cm⁻¹ (6,7 – ZPL), 83 620 cm⁻¹ (8 – ZPL, 6,7 - vibronic band), 83 920 cm⁻¹ (9 – ZPL; the maximum is not reproduced well due to the underestimated transition intensity), 84 320 cm⁻¹ (12 – ZPL), 84 620 cm⁻¹ (14,15 – ZPL, 12 – vibronic band).

The intensities of transitions from the ground state ${}^{1}S_{0}(4f^{14})$ to the lowest quasidoublet (1,2) in the $4f^{13}5d$ configuration equal zero (in Condon approximation), however the corresponding ZPL energies are at the threshold of the weak feature in the observed excitation spectrum (see Fig. 8). Besides, the first state is positioned in the middle between the first feature in the emission spectrum (81 035 cm⁻¹) and the first maximum of the weak feature in the excitation spectrum (81 240 cm⁻¹). This supports the hypothesis of Sec. III B 2, that the phonon-assisted spin-forbidden $4f^{14}-4f^{13}5d$ transitions are observed in these spectra.

We simulated the absorption and emission spectra for the forbidden transitions utilizing Eqs. (9)-(11). The results of calculations are compared with the weak feature observed in LiYF₄:Lu³⁺(5%) excitation spectrum and with the LiYF₄:Lu³⁺(0.5%) emission spectrum in Fig. 12. The agreement is satisfactory, especially for the emission spectrum (no additional fitting has been done). Only the term $\int F_{ab}(\Omega)$ $-\omega f(\omega)d\omega$ brings about significant contribution to the form function $K_{ab}^{(f)}(\Omega)$ [see Eq. (9)] for the forbidden transitions under investigation. This explains the absence of the ZPLs in experimental emission and excitation spectra corresponding to the spin-forbidden transitions in $LiYF_4$: Lu^{3+} , and leads to symmetric calculated spin-forbidden absorption and emission spectra. The fine structure in the calculated spectra comes from a convolution of the ZPL in $F_{ab}(\Omega)$ with $f(\omega)$ and reproduces the spectral distributions of the electronphonon coupling between the lowest quasidoublet and other



FIG. 12. The low temperature simulated (1, dashed curve) and measured (2, thin solid curve) emission spectra; simulated (3, bold solid curve) and measured (4, dotted curve) excitation spectra in the region of $Lu^{3+} 4f$ -5d spin-forbidden transitions in LiYF₄:Lu³⁺.

crystal field states in the excited configuration. Other terms in $F_{ab}(\Omega)$ lead to higher order convolutions of $g_{\alpha\beta}(Ls, L's' | \omega)$ spectral densities, with the fine structure smoothed out.

The calculated integral intensities of phonon-induced electric dipole transitions involving the first and the second $4f^{13}5d$ states, defined by $\int f(\omega)d\omega$, are given in parentheses in Table II. The magnitude of the simulated nonpolarized excitation curve for the forbidden transitions is of the same order as the experimental one, once the scaling coefficient was established in Fig. 11.

IV. CONCLUSIONS

The VUV $4f^{n-1}5d-4f^n$ luminescence and luminescence excitation spectra of various Gd³⁺ and Lu³⁺ containing fluorides have been analyzed with high spectral resolution. Gd³⁺ ions emit only fast (nanosecond) spin-allowed 5*d*-4*f* luminescence as it is typical for RE³⁺ ions from the first half of the lanthanide series. At low temperatures, Lu³⁺ ions emit exclusively slow spin-forbidden 5*d*-4*f* luminescence. With increasing temperature, however, an admixture of spinallowed 5*d*-4*f* emission shows up. Strong electron-phonon coupling has been observed from REF₃-type systems, whereas the spectra of the more complex LiREF₄ systems exhibit intermediate coupling with zero-phonon lines (Gd³⁺) and phonon sidebands.

Spectral envelopes of some of the spectra have been simulated as well. Contrary to earlier attempts to calculate VUV 5*d*-4*f* luminescence and luminescence excitation spectra where electron-phonon interaction was simulated with Gaussian broadening of electronic excitations and Gaussian sidebands in luminescence,⁴⁵ the present theoretical results originate from a microscopic semiphenomenological model of the crystal field and the crystal lattice vibrational spectrum. The simulations were restricted to the Ce³⁺ and Lu³⁺ ions with simple 4*f* ⁰5*d* and 4*f* ¹³5*d* electronic configura-

tions, respectively. Good agreement between experiment and theory was achieved. The absence of a ZPL in the Lu³⁺ spectra with intermediate electron-phonon coupling was also obtained from the simulation of the spin-forbidden spectrum. Concerning the more complicated case of Gd^{3+} with its $4f^{6}5d$ electronic configuration, the luminescence spectra were calculated in an indirect way. Based on the observation that the $Gd^{3+} 5d-4f$ luminescence spectrum in LiYF₄ is very similar to the excitation spectrum of the Ce³⁺ 5d-4f emission in the same host, the spectra were calculated for the Ce³⁺ ion. In this way, it was possible to identify the phonon structures in the Gd³⁺ luminescence spectra. It is the *combination* of the high-resolution spectra with their theoretical treatment that brought about an understanding of Gd³⁺ and Lu³⁺ 5d-4f lu-

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